

TOF measurements with MCP's

J. Va'vra, SLAC

Light travels 300 μm in one ps

Point this talk

- **Two possible directions to make a TOF counter:**

- **High gain MCP operation**

- detector is **sensitive to single photoelectrons**.
 - excellent TOF resolution of 5-10 ps; thin radiator of 3-5 mm possible.
 - possibly serious QE aging problems.

SuperBelle: MCP rate of single pe's could be easily **> 100 kHz/cm²** at $L \sim 10^{36}/\text{cm}^2/\text{sec}$
(TOP counter in the barrel region)

- **Low gain MCP operation**

- detector is **sensitive to tracks only**, and not sensitive to single photoelectrons.
 - Somewhat worse TOF resolution of 15 ps; thicker radiator of 7-10 mm.
 - possibly much smaller QE aging problems.

SuperB: MCP track rate is expected to be only **< 2 kHz/cm²** at $L \sim 10^{36}/\text{cm}^2/\text{sec}$
(Forward TOF counter in the endcap region)

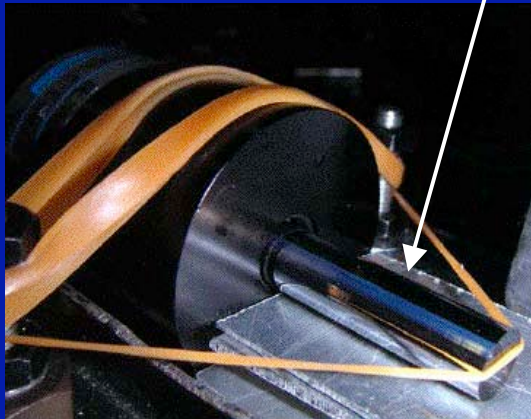
High gain operation

Example: Nagoya TOF counter

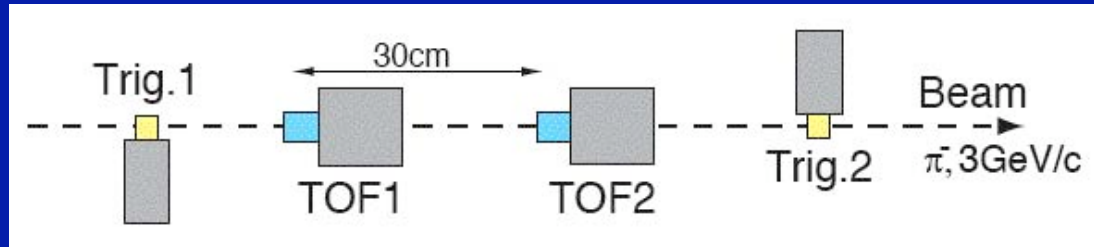
The Nagoya test in the beam

K. Inami, H. Kishimoto, Y. Enari, M. Nagamine, and T. Ohshima, “ A 5 ps TOF-counter with MCP-PMT”,
Nucl. Instr. & Meth., A560(2006)303-308.

Vary the length



Beam test setup: two identical TOF detectors



- **Quartz radiator:** 10 mm dia. rod, coated with Al on its round sides, and Length: 40, 30, 20, 10 mm and no radiator (just a 3 mm quartz window).
- They claim: $N_{pe} \sim 20$ for $L = 3$ mm, and $N_{pe} \sim 40-50$ for $L = 10 + 3$ mm.
- The best resolution result was obtained for $L = 10 + 3$ mm.

Hamamatsu MCP-PMT TTS measurement

Hamamatsu data sheets

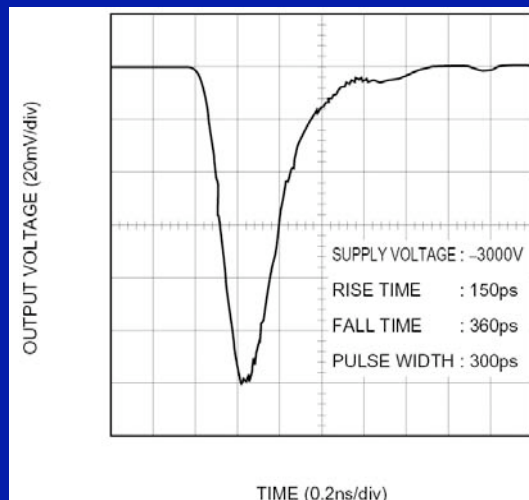
MCP-PMT R3809U-50:



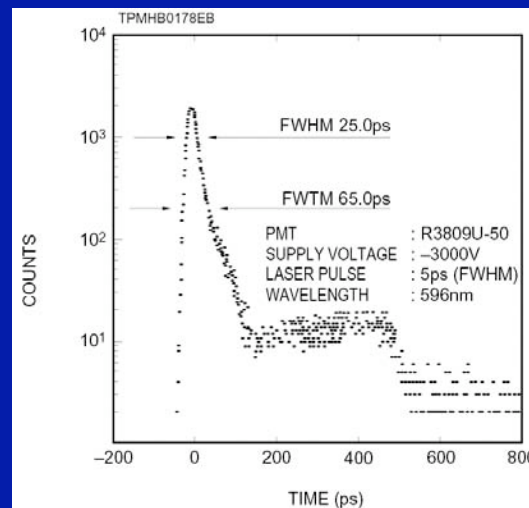
- **6 μm MCP hole diameter**
- Useful photocathode dia.: **11 mm**, Single pixel device
- Rise time: **~ 150 ps.**
- **Multi-alkali photocathode** (NaKSbCs), **QE $\sim 26\%$** at 407nm.
- MCP-to-anode capacitance: **$\sim 3\text{pF}$**
- **$\sigma_{\text{TTS}} = 10\text{-}11$ ps**
- HPK C5594-44 amp., **1.5 GHz BW**, **63x gain**
- Laser light source jitter contribution: **$\sigma \sim 2.1$ ps**
(Red wavelength of Nd-YAG laser: **$\lambda = 596$ nm**)



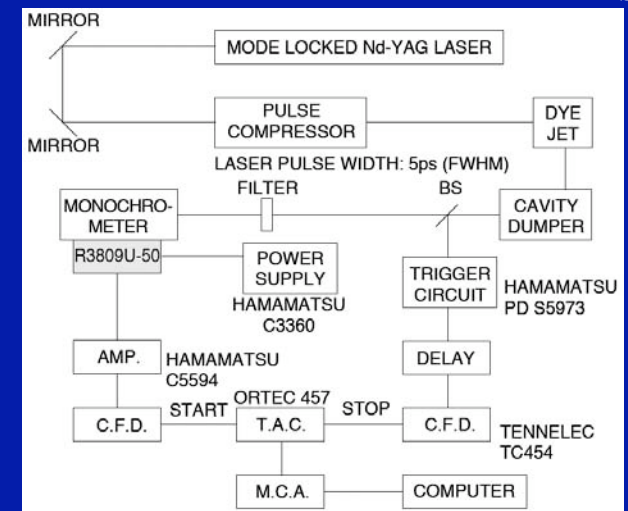
Rise time: $\sim 150\text{ps}$



TTS distribution:



Nd-YAG laser setup to measure σ_{TTS} :

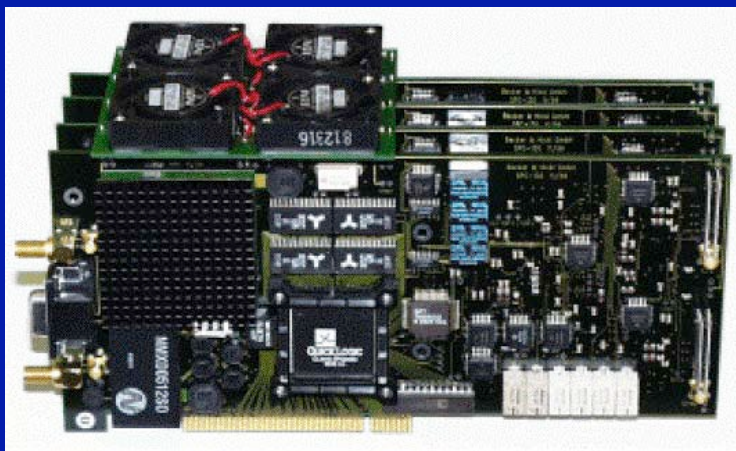


Electronics resolution

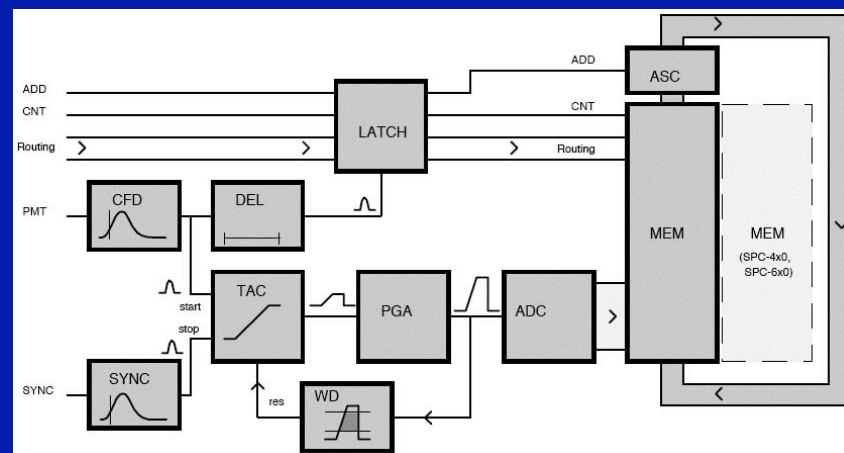
K. Inami, H. Kishimoto, Y. Enari, M. Nagamine, and T. Ohshima, “A 5 ps TOF-counter with MCP-PMT”, Nucl. Instr. & Meth., A560(2006)303-308.

Time-correlated single photon counting module :

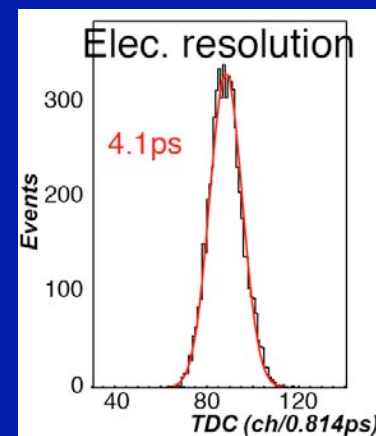
Becker & Hickl GmbH **SPC-134**



CFD/TAC/ADC



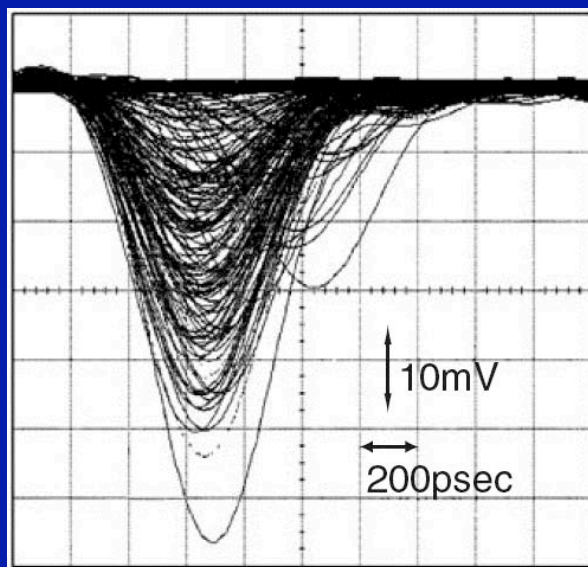
- **813 fs / count**
- **Time resolution achieved: $\sigma_{\text{Electronics}} \sim 4.1$ ps**
- **This result is slightly better than our Fermilab test beam result, however, worse than my bench tests at SLAC. In other words, the Ortec CFD/TAC/ADC electronics pretty good.**



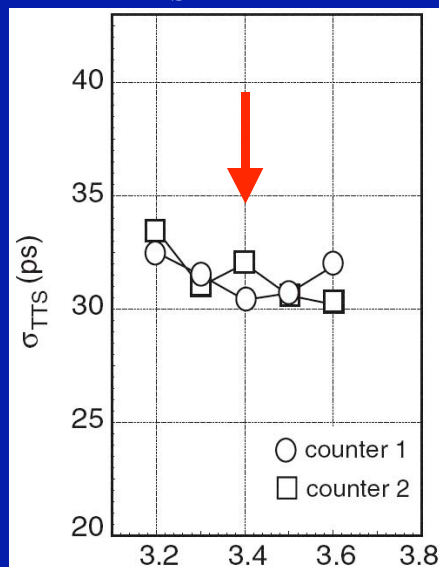
Single photoelectron response with a laser

K. Inami, H. Kishimoto, Y. Enari, M. Nagamine, and T. Ohshima, "A 5 ps TOF-counter with MCP-PMT", Nucl. Instr. & Meth., A560(2006)303-308.

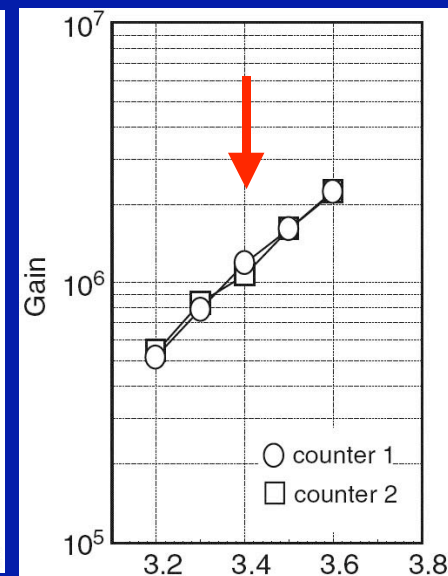
MCP-PMT R3809U-50:



$\sigma_{TTS} = f(HV)$



Gain = f(HV)



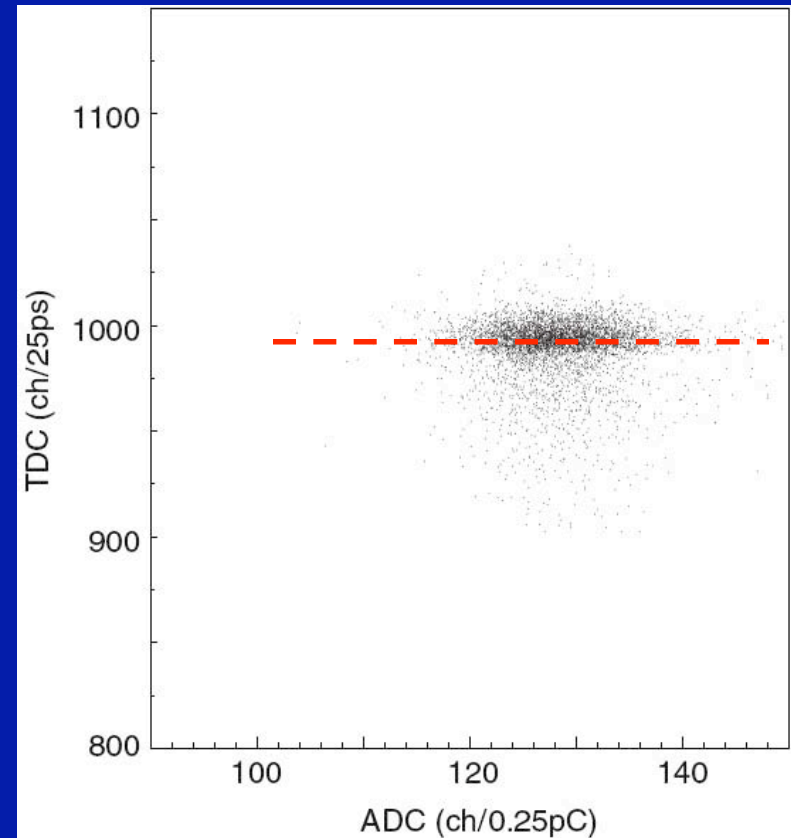
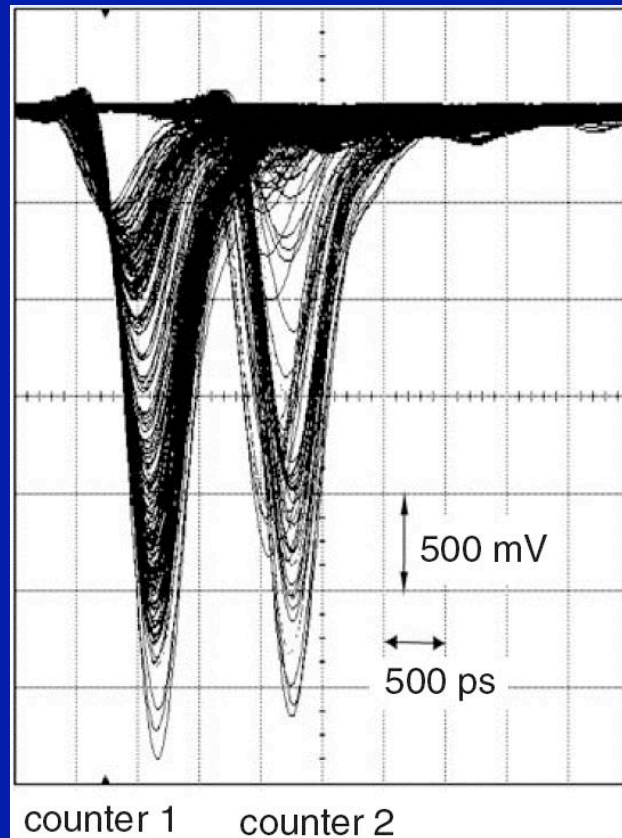
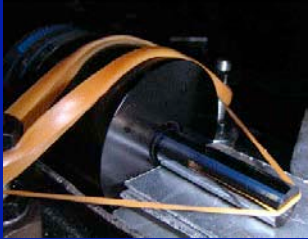
HV [kV]

HV [kV]

- They operated the device at a very high gain of $\sim 2 \times 10^6$ at 3.4 kV.
- They measure $\sigma_{TTS} \sim 32$ ps, even though Hamamatsu says $\sigma_{TTS} \sim 10$ -11 ps.
- No reply when I asked why they did not use the Hamamatsu number.
- Inami told me that they have operated the beam test without an amplifier.
- No reply to my question if pulses saturated for longer radiators.

Detector response in the beam

K. Inami, H. Kishimoto, Y. Enari, M. Nagamine, and T. Ohshima, "A 5 ps TOF-counter with MCP-PMT", Nucl. Instr. & Meth., A560(2006)303-308.



- No dependence of timing on ADC - in contrast to our test at Fermilab
- No amplifier used in the Nagoya test.

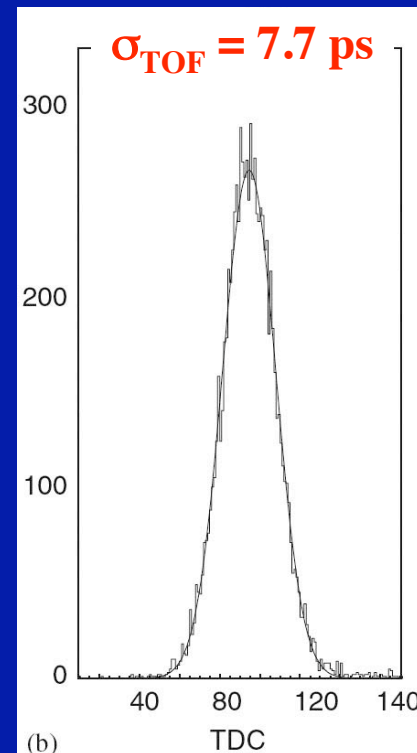
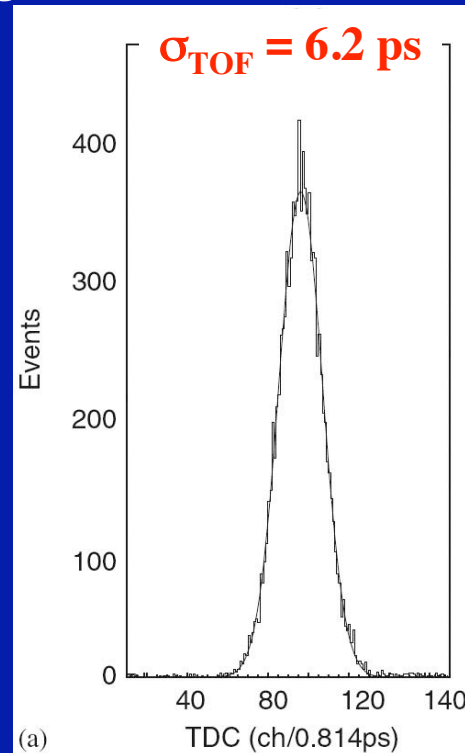
The best beam results so far

K. Inami, H. Kishimoto, Y. Enari, M. Nagamine, and T. Ohshima, “A 5 ps TOF-counter with MCP-PMT”,
Nucl. Instr. & Meth., A560(2006)303-308.

Quartz radiator length: **10 + 3 mm**

3 mm

Single
detector
resolution:

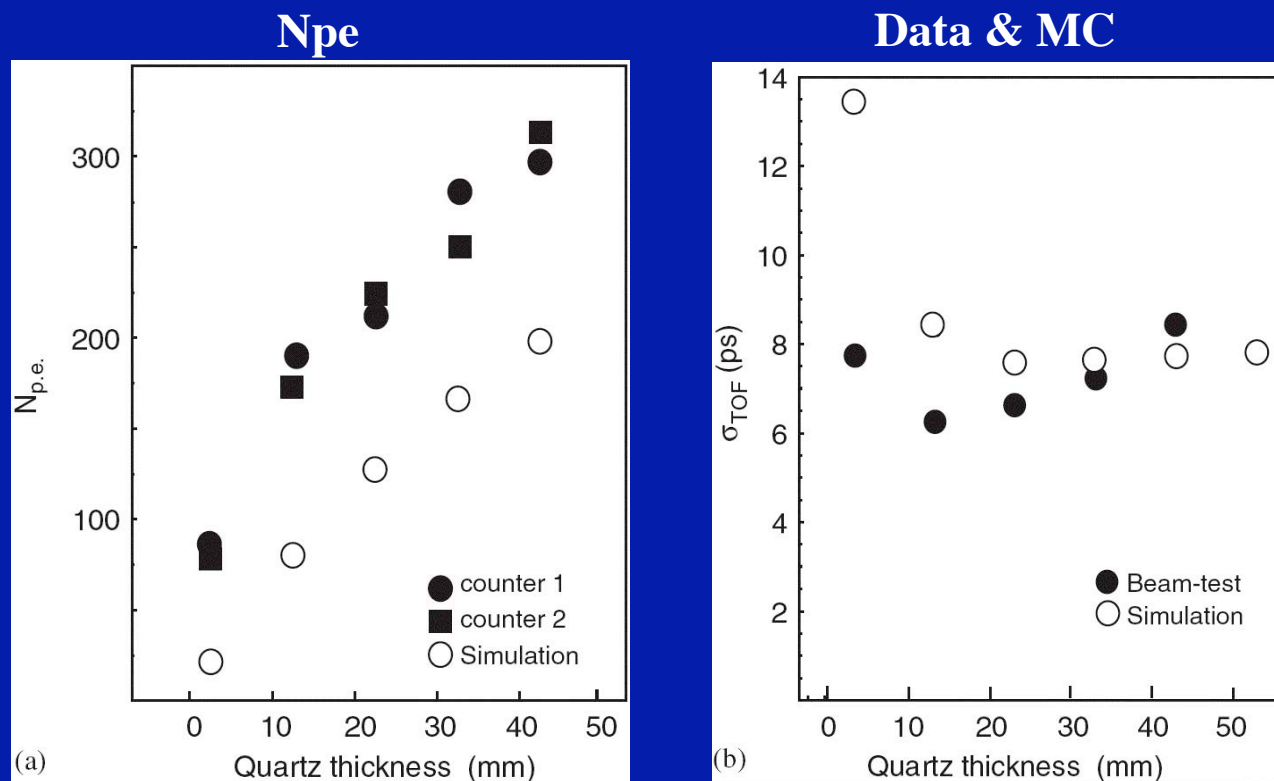


$$\sigma_{\text{TOF}} = \sigma_{\text{measure}}/\sqrt{2}$$

- Two identical HPK MCP-PMT R3809U-59-11 with **6 μm holes**.
- MCP-PMT operated at a very high gain of **$\sim 2 \times 10^6$** .
- No amplifier to avoid saturation effects in CFD timing

How well do we understand it with MC ?

K. Inami, H. Kishimoto, Y. Enari, M. Nagamine, and T. Ohshima, "A 5 ps TOF-counter with MCP-PMT", Nucl. Instr. & Meth., A560(2006)303-308.



- **Mystery #1: Measured number of Npe is SIGNIFICANTLY larger than expected.**
- **Mystery #2: MC does not reproduce data well.**
- **Mystery #3: L = 10 mm gives the best resolution; MC predicts L = 20-30 mm.**

A simple calculation ?

My version of simple model (Nagoya people have similar but less correct formula in the paper)

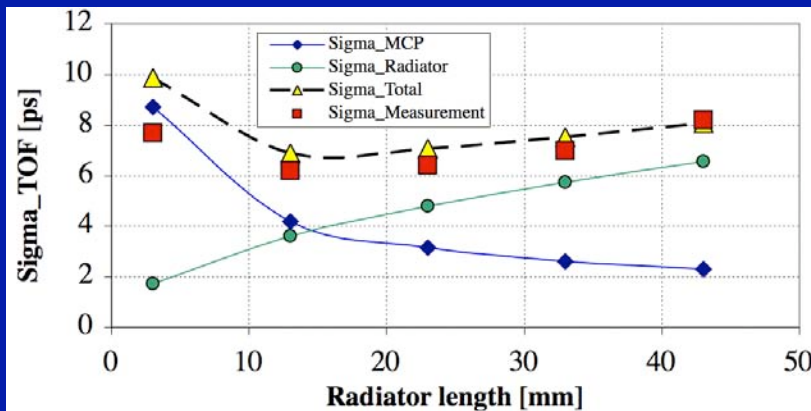
$$\sigma_{\text{TOF}} \sim \sqrt{[\sigma_{\text{MCP-PMT}}^2 + \sigma_{\text{Radiator}}^2 + \sigma_{\text{Pad broadenibng}}^2 + \sigma_{\text{Electronics}}^2]} =$$

$$= \sqrt{[(\sigma_{\text{TTS}}/\sqrt{N_{\text{pe}}})^2 + (((L*1000\mu\text{m}/\cos\Theta_C)/(300\mu\text{m}/\text{ps})/n_{\text{group}})/\sqrt{(12N_{\text{pe}})})^2 +$$

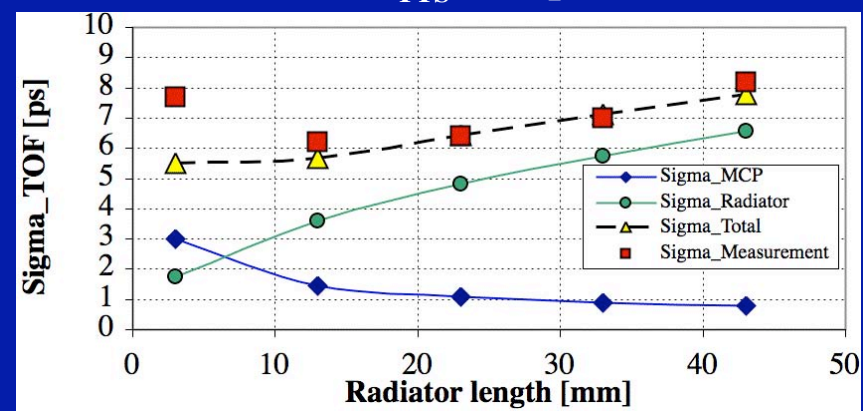
$$+ ((5*1000\mu\text{m}/300\mu\text{m}/\text{ps})/\sqrt{(12N_{\text{pe}})})^2 + (4.1 \text{ ps})^2]}$$

For $L = 13 \text{ mm}$: $\sigma_{\text{TOF}} \sim \sqrt{[4.18^2 + 3.6^2 + 0.63^2 + 4.1^2]} \sim 6.9 \text{ ps}$

Assume $\sigma_{\text{TTS}} \sim 32 \text{ ps}$:



Assume $\sigma_{\text{TTS}} \sim 11 \text{ ps}$:



- A simple model actually does work quite well, if one assumes $\sigma_{\text{TTS}} \sim 32 \text{ ps}$.
- Assume, as Nagoya people suggest: $N_{\text{pe}} = 40\text{-}50 \text{ pe} / L = 10 \text{ mm}$
- Assume a beam size = acceptance of a 5 mm x 5 mm beam counter.

Low gain operation

Example: SLAC TOF counter

Tests with Photonis MCP-PMT

MCP-PMT 85012-501:



- **10 μm MCP hole diameter**
- 64 pixel devices, pad size: 6 mm x 6 mm.

PiLas red laser diode operating in the single photoelectron mode (635 nm):

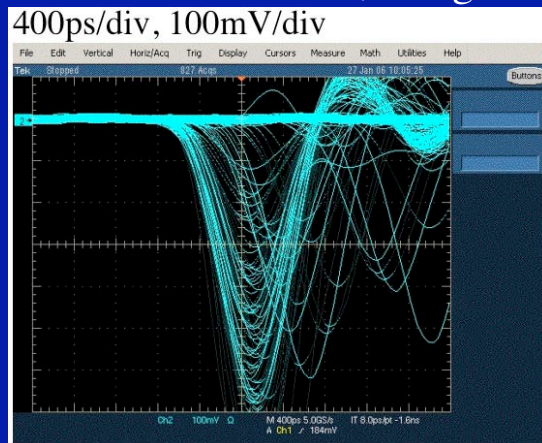
$$\sigma_{\text{TTS}} < \sqrt{(32^2 - 13^2 - 11^2)} = 27 \text{ ps}$$

PiLas laser diode Electronics (TDC mainly)

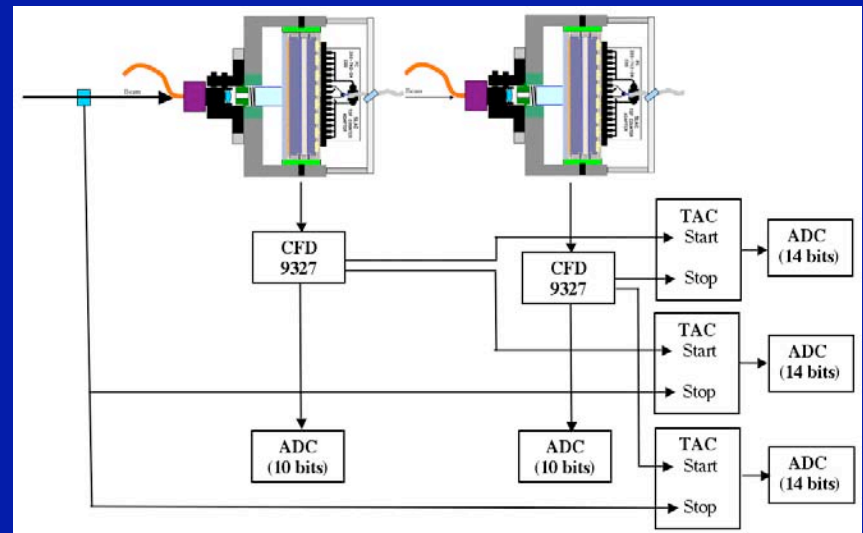


Hamamatsu C5594-44 amplifier

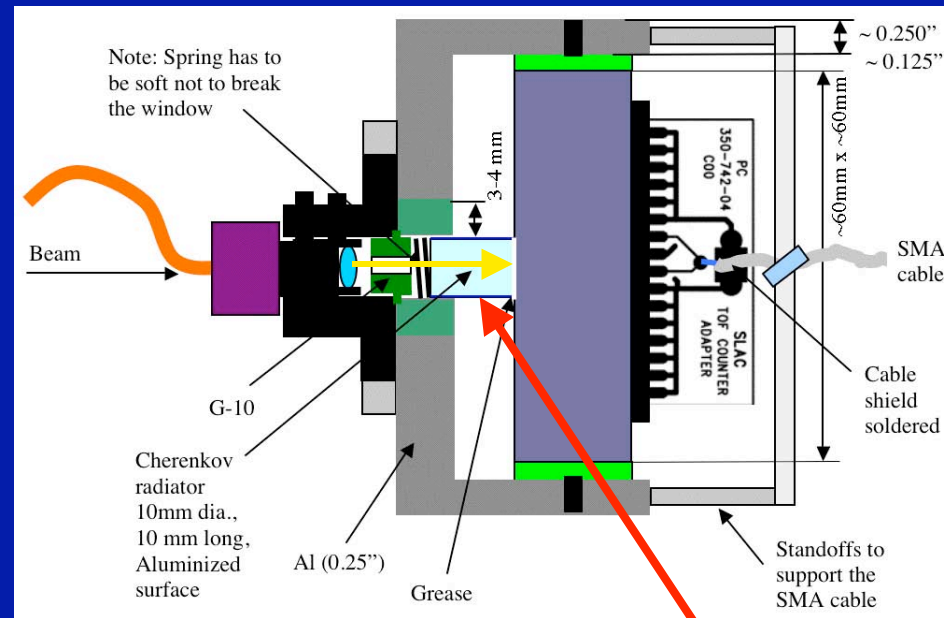
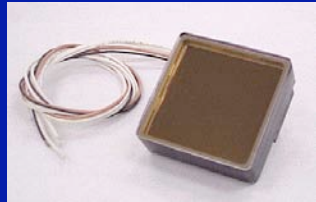
1.5 GHz BW, 63x gain



Two identical counters in the beam:



SLAC TOF counter prototype

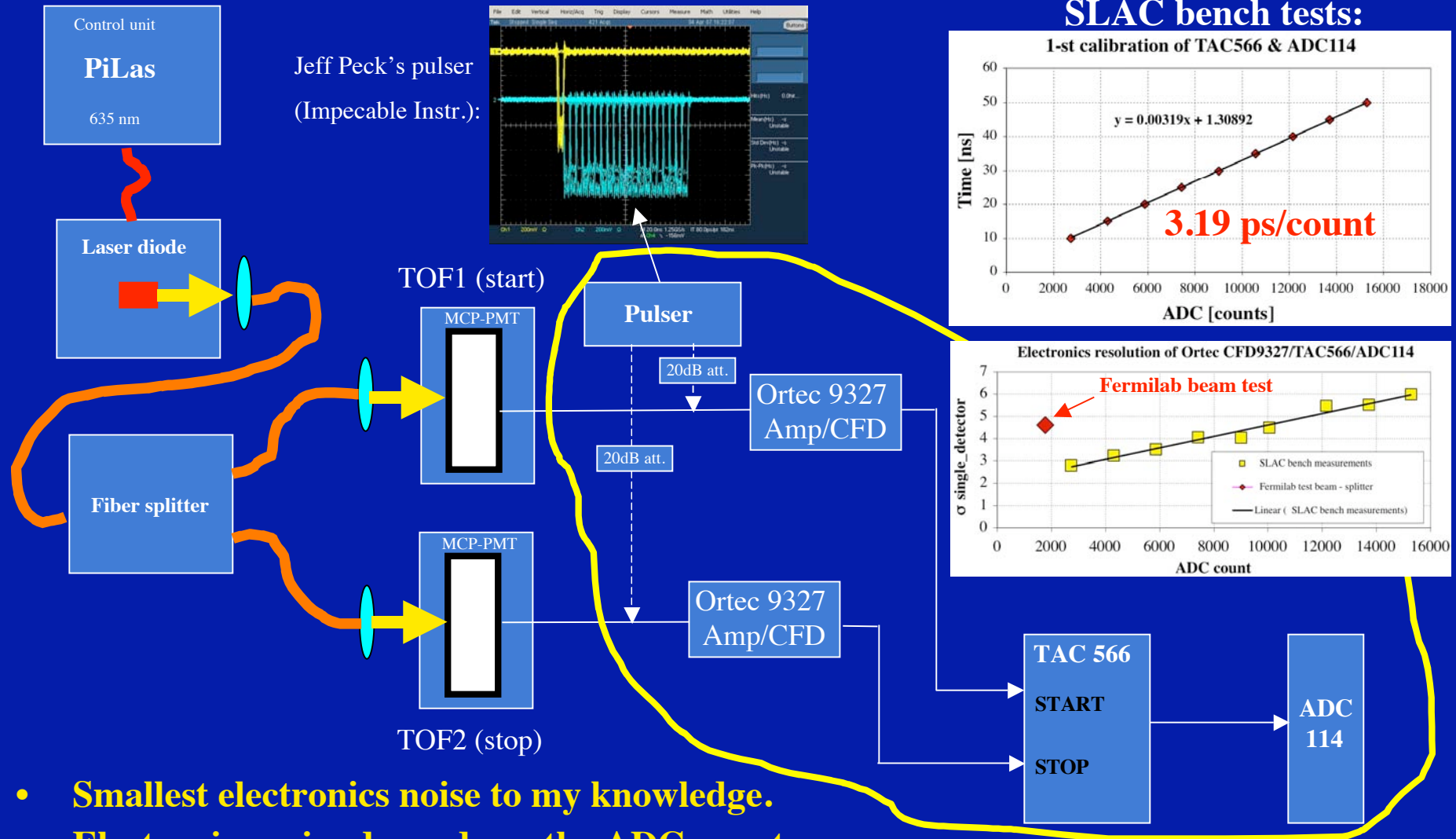


Cylindrical radiator coated with Al on its sides

- Concentrate light on 4 pads to increase S/N to be able to run low gain
- Short together 4 pads to get a signal; all the rest of pads grounded.
- A 10mm-long, 10mm dia, quartz radiator, Al-coating on cylinder sides.

Electronics resolution in the Ortec CFD/TAC/ADC system

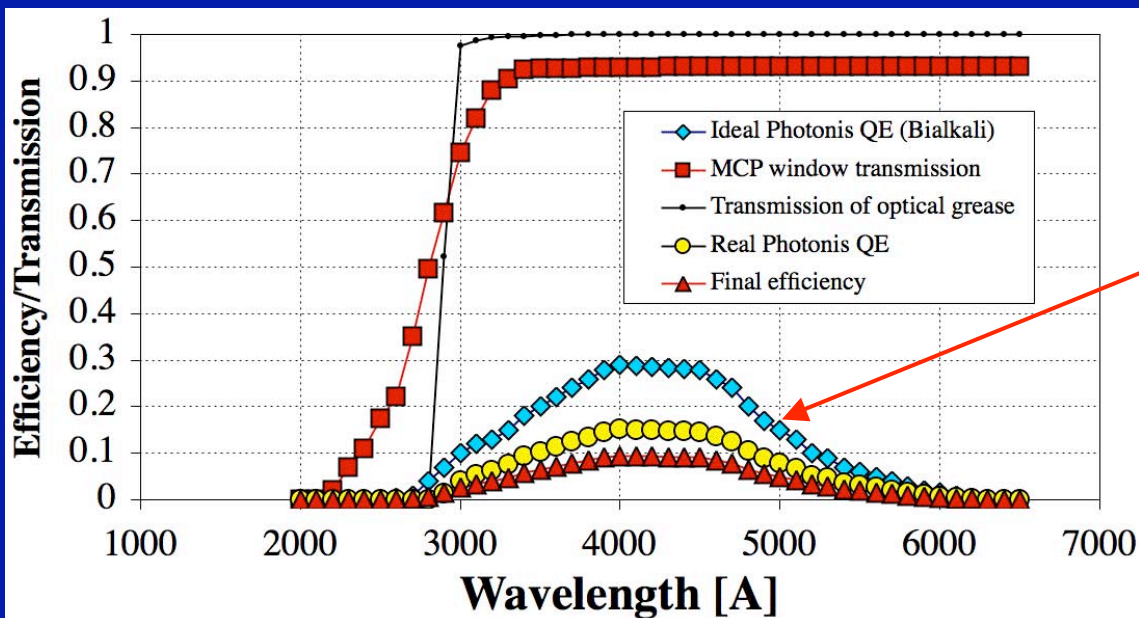
J.Va'vra, MCP-PMT log book 4



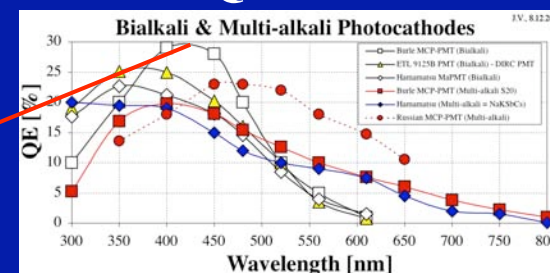
- **Smallest electronics noise to my knowledge.**
- **Electronics noise depends on the ADC count.**
- **Fermilab test beam electronics noise slightly worse than in SLAC bench tests.**

Expected Npe

Wavelength bandwidth of this TOF counter:



QE



Scale down the “optimistic” Burle QE using a luminous sensitivity in blue provided by Photonis for this particular tube

- **Calculation using all known efficiencies: $N_{pe} \sim (30 + 42)/2 \sim 36$.**
- **Scope test in the Fermilab beam test: $N_{pe} \sim 45 \pm 10$.**

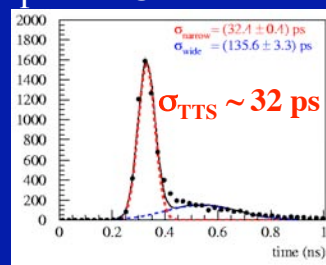
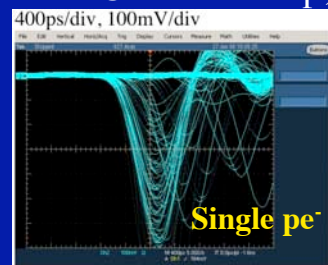
[Procedure to determine N_{pe} : (a) scope measurement of average PH, (b) scope measurement of a cable delay, (c) measure amplifier amplitude attenuation for the same cable delay, (d) gain correction due to a different voltage used in my best resolution measurement]

Planacon σ_{TTS} at very high gain

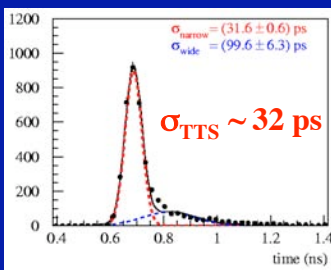
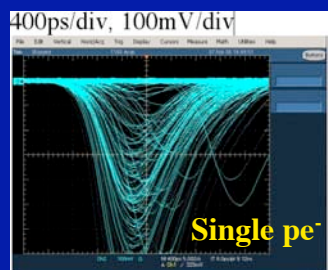
J.Va'vra et al., Nucl.Instr.&Meth. A 572 (2007) 459–462, and my log books 3 & 6, 2006 & 2008

1) ~300 MHz BW electronics:

HPK C5594-44 amp, Phillips 715 CFD:

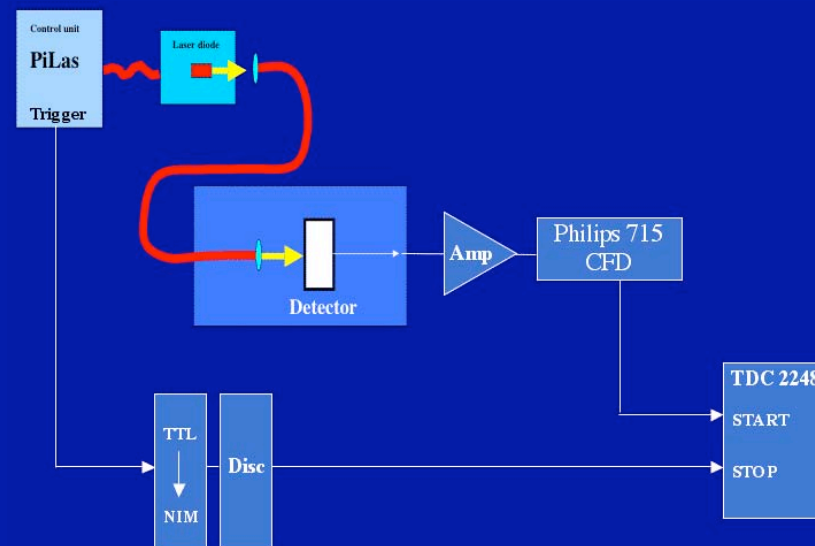


Ortec VT-120 amp.+6dB, Phillips 715 CFD :



- Slow down amplifiers by a long cable between Amp & CFD (optimum was found to be ~20ns).

- **Photonis Planacon**, S/N 11180401
- **10 μ m MCP hole diameter**
- **2.8 kV**
- **Single pe sensitivity**

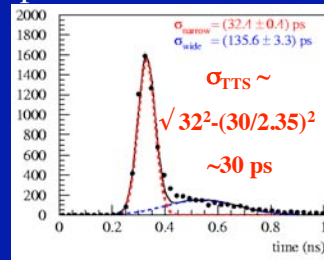
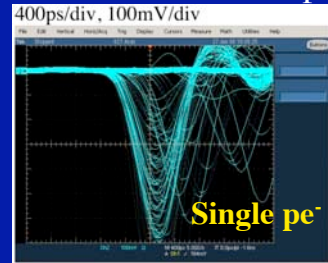


Planacon σ_{TTS} at very high gain

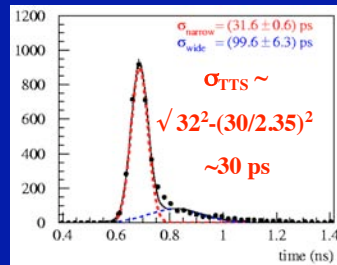
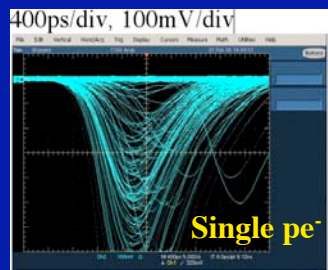
J.Va'vra et al., Nucl.Instr.&Meth. A 572 (2007) 459–462, and my log books 3 & 6, 2006 & 2008

1) ~300 MHz BW electronics:

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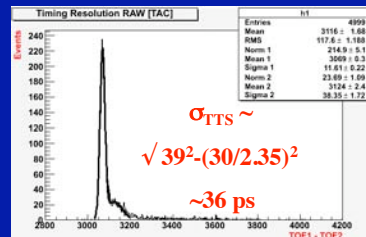
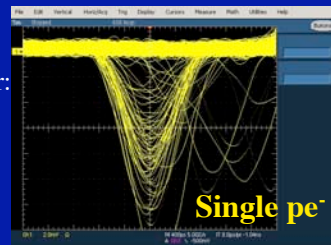


- Slow down amplifiers by a long cable between Amp & CFD (optimum was found to be ~20ns).

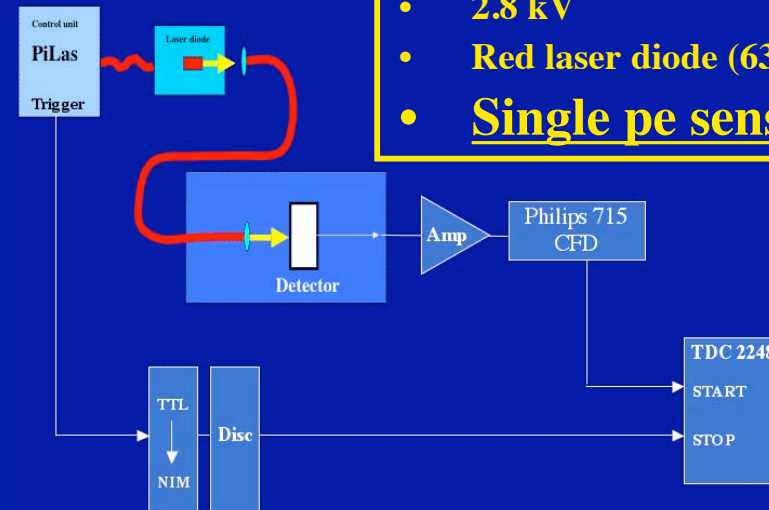
2) ~1 GHz BW electronics:

Ortec 9327CFD, TAC566, ADC114:

CFD monitor:



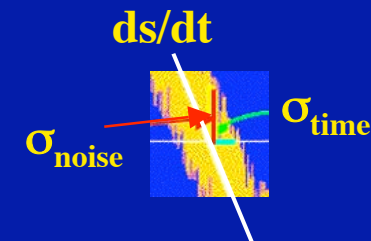
3/4/09



- Photonis Planacon, S/N 11180401
- 10 μm MCP hole diameter
- 2.8 kV
- Red laser diode (635 nm)
- Single pe sensitivity

CFD timing:

$$\sigma_{\text{time}} = \sigma_{\text{noise}} / (ds/dt)_{\text{zero crossing point}}$$



Note:

The best results obtained with slower electronics

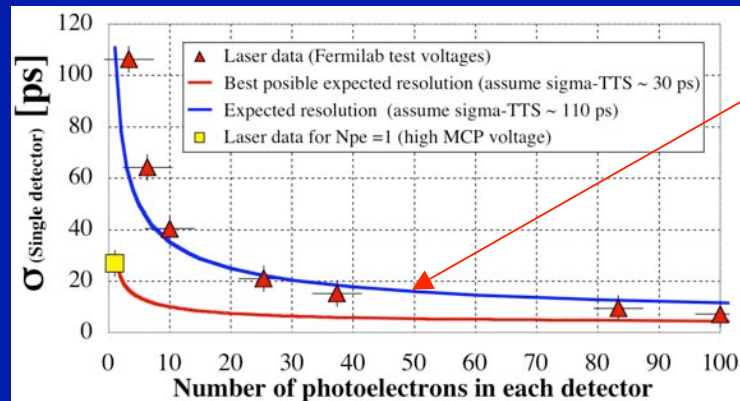
J. Va'vra, ps workshop, Argonne lab

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σ_{TTS} at low gain - the same condition as during the beam test

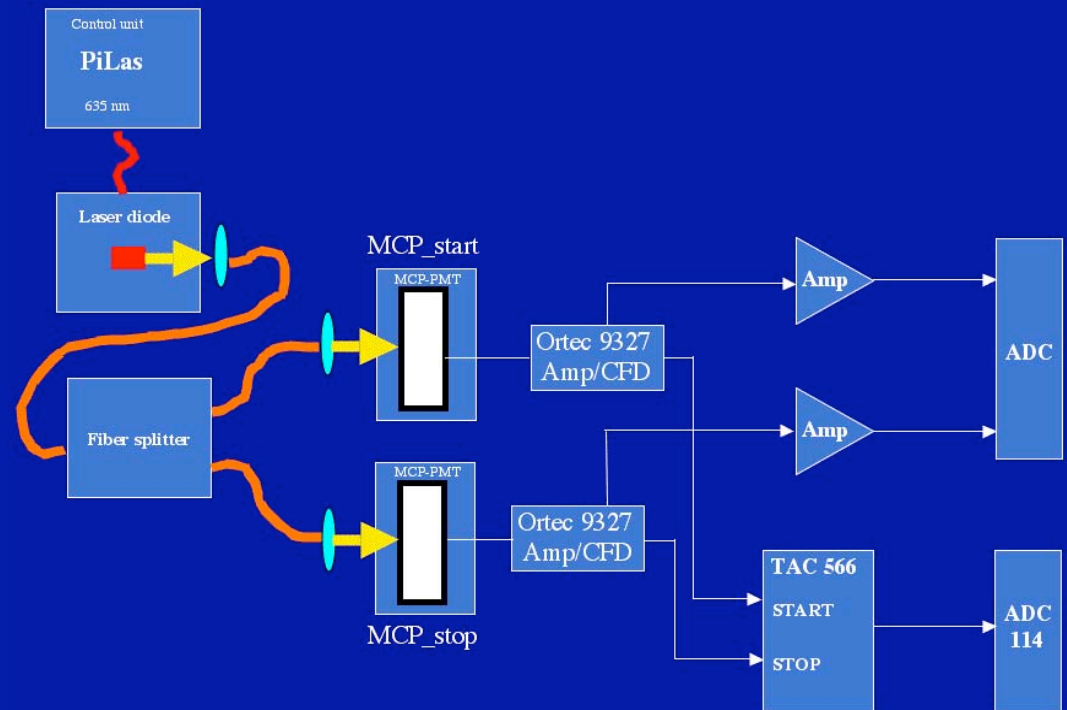
J.Va'vra et al., Nucl.Instr.&Meth. A 595 (2008) 270-273

Nominal MCP voltages, $G \sim 2 \times 10^4$:



$$\sigma \sim \sqrt{[\sigma_{MCP-PMT}^2 + \sigma_{Laser}^2 + \sigma_{Electronics}^2 + \dots]} = \sqrt{[\sigma_{TTS}/\sqrt{N_{pe}}]^2 + \sqrt{((FWHM/2.35)/\sqrt{N_{pe}})^2 + (3.1 \text{ ps})^2}}$$

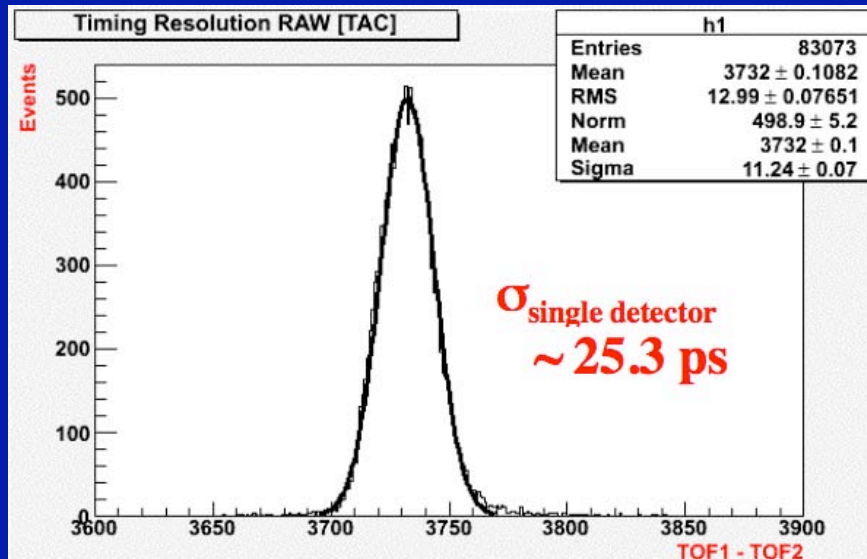
- **Photonis Planacon**, S/N 11180401 & 7300714
- **10 μm MCP hole diameter**
- **2.2 kV & 2.0 kV on MCP-PMTs**
- **Red laser diode (635 nm)**
- **Not sensitive to single pe**
- **Linear for Npe \sim 30-50**



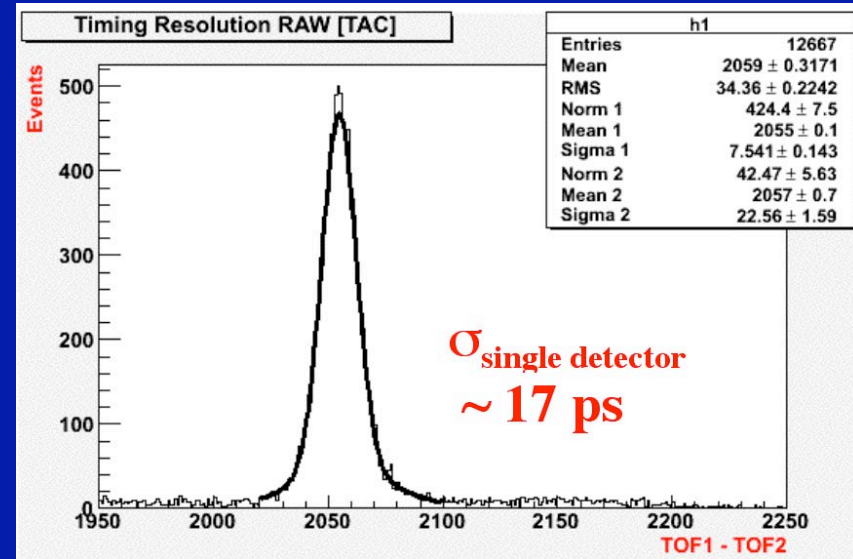
- The same electronics as in the test beam - Ortec electronics (9327CFD, TAC566, ADC114)
- Extrapolating to $N_{pe} = 1$, one obtains much worse $\sigma_{TTS} \sim 120 \text{ ps}$.

Beam tests at SLAC and Fermilab

SLAC beam test, 10 GeV e^+ :



Fermilab beam test, 120 GeV p:

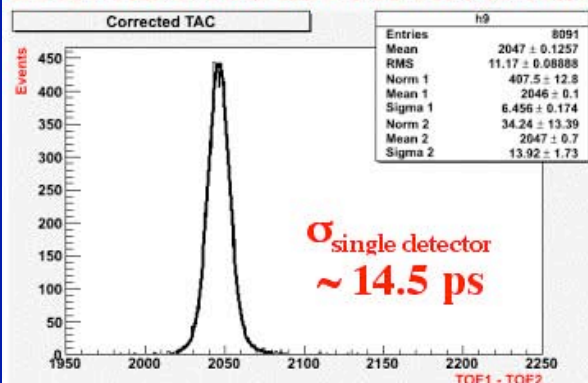


- All events - no ADC cuts or ADC corrections to timing in these two plots.
- Difference between two tests: use a new quartz radiator with a new aluminum coating in the in Fermilab test (coated by Photonis).

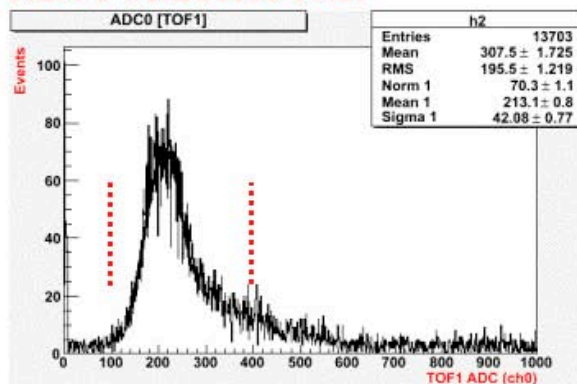
Beam test at Fermilab

120 GeV protons:

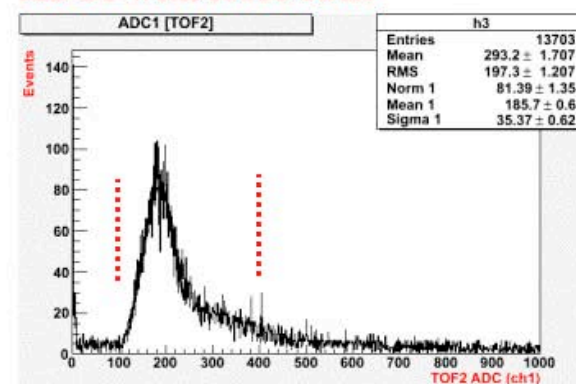
Loose ADC cuts and PH correction:



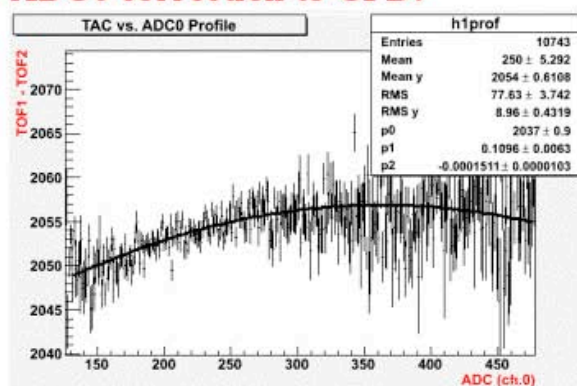
ADC0 with loose cuts:



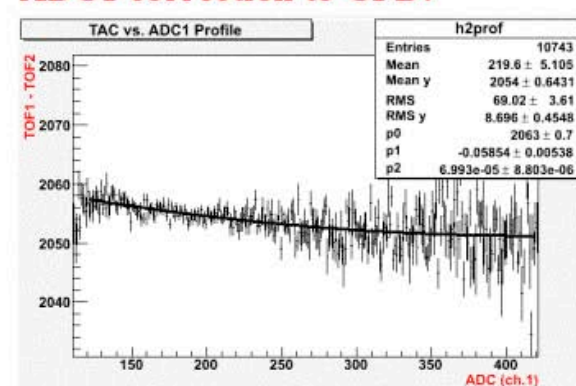
ADC1 with loose cuts:



ADC0 correction to CFD:



ADC1 correction to CFD:

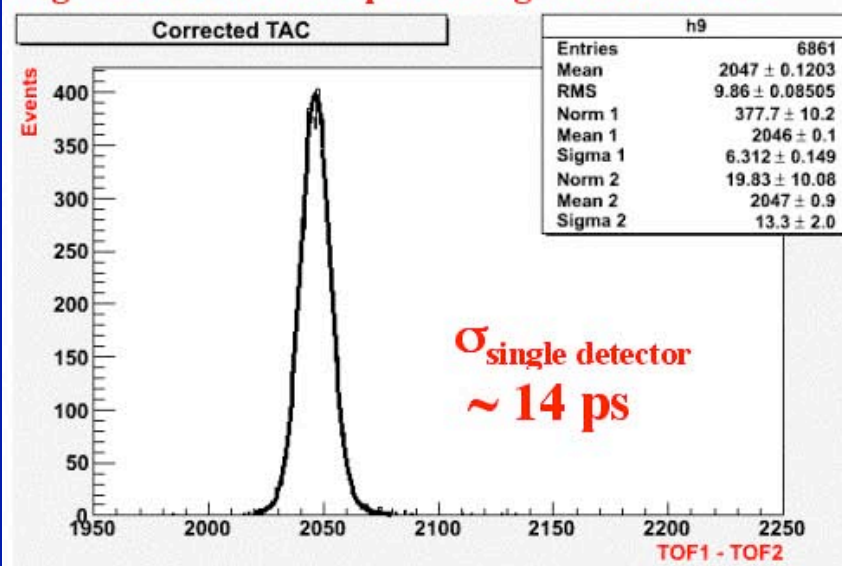


- ADC correction to CFD timing & loose ADC cuts

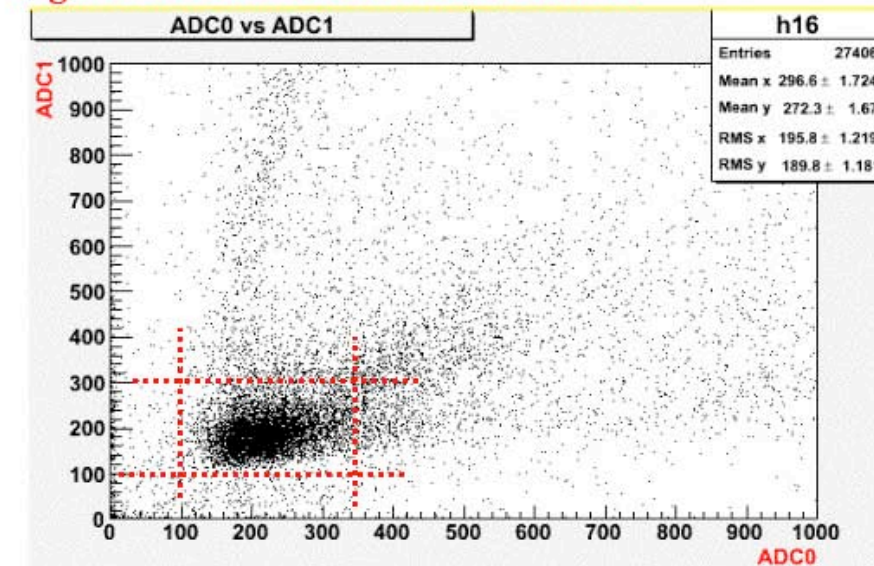
Beam test at Fermilab

120 GeV p:

Tight ADC cuts and pulse height correction:



Tight ADC cuts to eliminate doubles:



- ADC correction to CFD timing & tighter ADC cuts

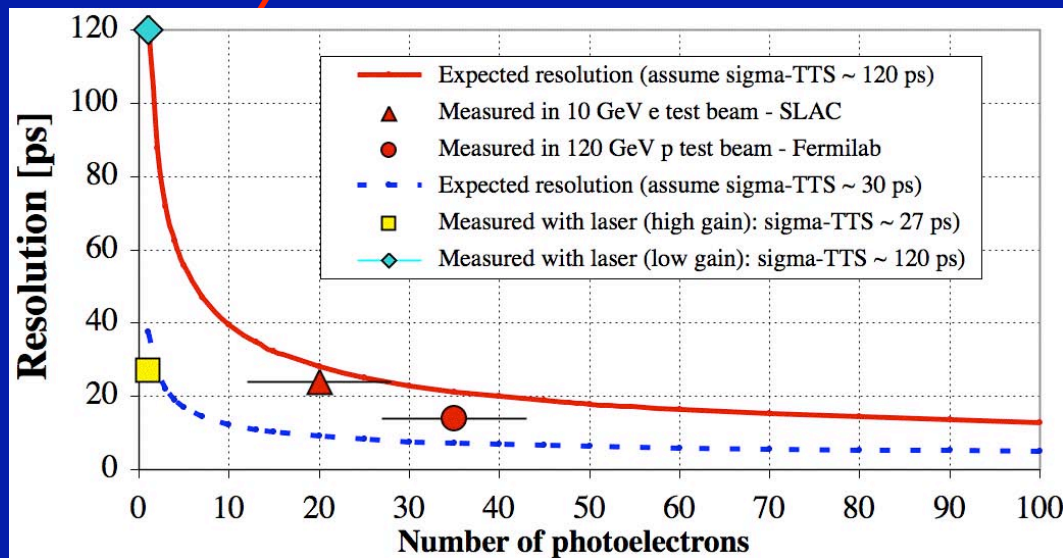
Are the results consistent with expectations ?

$$\sigma_{\text{TOF}} \sim \sqrt{[\sigma_{\text{MCP-PMT}}^2 + \sigma_{\text{Radiator}}^2 + \sigma_{\text{Pad broadening}}^2 + \sigma_{\text{Electronics}}^2 + \dots]} =$$

$$= \sqrt{[(\sigma_{\text{TTS}}/\sqrt{N_{\text{pe}}})^2 + (((12*1000\mu\text{m}/\cos\Theta_C)/(300\mu\text{m/ps})/n_{\text{group}})/\sqrt{(12N_{\text{pe}}))^2 +$$

$$+ ((6*1000\mu\text{m}/300\mu\text{m/ps})/\sqrt{(12N_{\text{pe}}))^2 + (4.7\text{ ps})^2]} \sim \mathbf{21.5\text{ ps}}$$

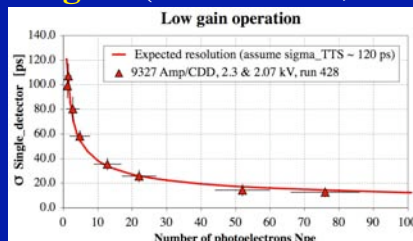
For $N_{\text{pe}} = 36$, contributions from each term: **20.3 ps 4.3 ps 3.4 ps 4.7 ps**



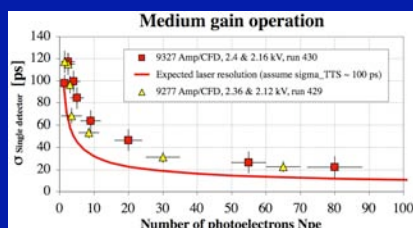
- Use a calculation for the Fermilab test: $N_{\text{pe}} \sim (30 + 42)/2 \sim 36$.
- In principle, one could choose to go via a very high gain route and follow the dashed blue curve to get into a 10 ps regime. For some applications it is possible to consider. To do that one has to consider amp. saturation effects.

$\sigma_{TTS} = f(\text{gain})$ with laser & test beam electronics

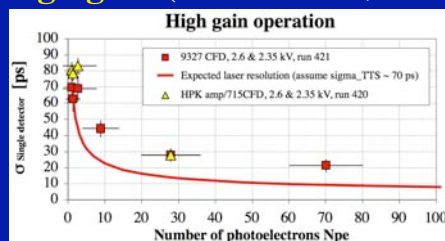
Low gain (2.3&2.07kV, $G \sim 2\text{-}3 \times 10^4$):



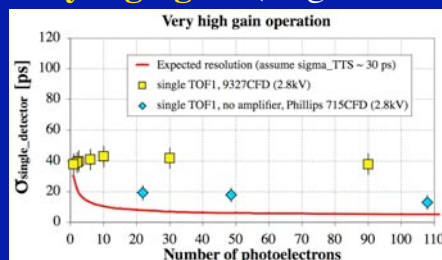
Medium gain (2.36&2.12kV, $G \sim 7 \times 10^4$):



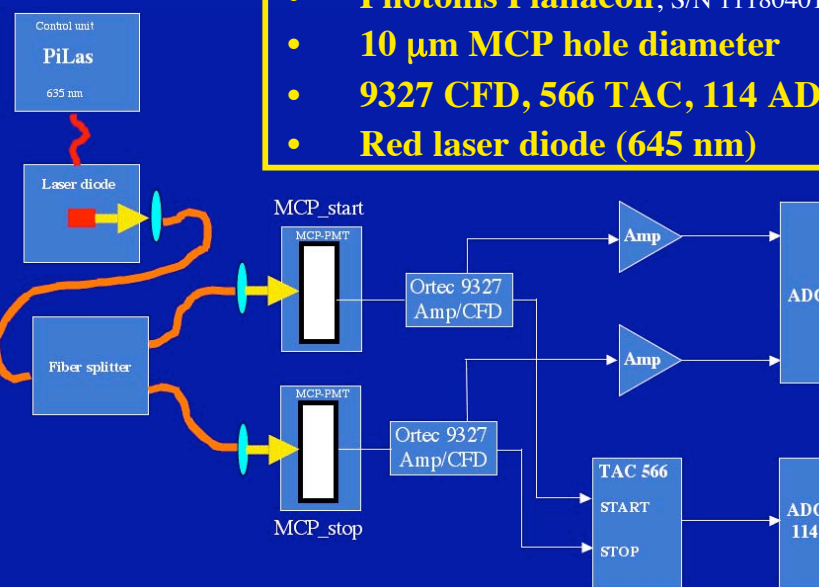
High gain (2.6&2.15kV, $G \sim 3 \times 10^5$):



Very high gain (single detector, 2.8 kV, $G \sim 10^6$):

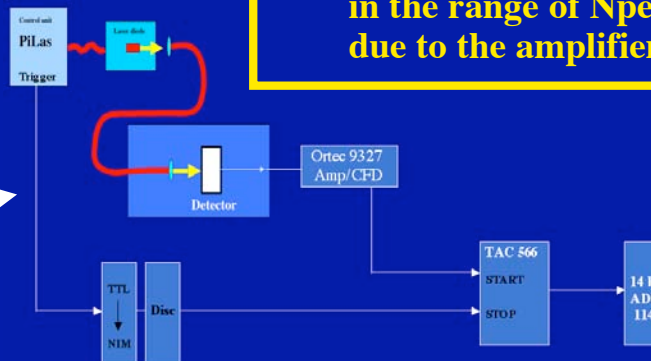


J.Va'vra, log book 6, 2008



- **Photonis Planacon**, S/N 11180401 & 7300714
- **10 μm MCP hole diameter**
- **9327 CFD, 566 TAC, 114 ADC**
- **Red laser diode (645 nm)**

- **Higher gain helps the σ_{TTS} measurement with 9327 CFD, however, it does not help in the range of $N_{pe} \sim 30\text{-}50$, presumably due to the amplifier saturation.**



3/4/09

J. Va'vra, ps workshop, Argonne lab

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Conclusions

- **I have outlined two clear choices how to proceed with MCP-based TOF counters:**
 - a) **One choice is to run a very high gain with single pe sensitivity, which could lead to a sub-ten ps TOF resolution. However, one may have serious lifetime issues requiring various QE protection solutions in a high bckg condition.**
 - b) **Another choice is a low gain operation, where the detector is sensitive to tracks only, which would lead to somewhat worse TOF resolution of ~15ps. On the other hand, one may have, possibly, longer QE lifetimes.**